

# DSS3515M-7B Datasheet



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	DSS3515M-7B-DG
Manufacturer	<a href="#">Diodes Incorporated</a>
Manufacturer Product Number	DSS3515M-7B
Description	TRANS PNP 15V 0.5A 3DFN
Detailed Description	Bipolar (BJT) Transistor PNP 15 V 500 mA 340MHz 2 50 mW Surface Mount X1-DFN1006-3



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## Purchase and inquiry

Manufacturer Product Number:

DSS3515M-7B

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

15 V

Current - Collector Cutoff (Max):

100nA (ICBO)

Power - Max:

250 mW

Operating Temperature:

-55°C ~ 150°C (TJ)

Package / Case:

3-UFDN

Base Product Number:

DSS3515

Manufacturer:

Diodes Incorporated

Product Status:

Active

Current - Collector (Ic) (Max):

500 mA

Vce Saturation (Max) @ Ib, Ic:

250mV @ 50mA, 500mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

150 @ 100mA, 2V

Frequency - Transition:

340MHz

Mounting Type:

Surface Mount

Supplier Device Package:

X1-DFN1006-3

## Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.21.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

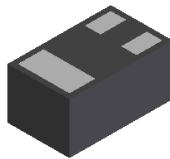
## Features

- $BV_{CEO} > -15V$
- $I_C = -500mA$  High Collector Current
- $I_{CM} = -1A$  Peak Pulse Current
- $P_D = 1000mW$  Power Dissipation
- Low Collector-Emitter Saturation Voltage,  $V_{CE(sat)}$
- $0.60mm^2$  Package Footprint, 13 Times Smaller than SOT23
- 0.5mm Height Package Minimizing Off-Board Profile
- Complementary NPN Type DIODES™ DSS2515M
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.**  
<https://www.diodes.com/quality/product-definitions/>
- **An automotive-compliant part is available under separate datasheet ([DSS3515MQ](#))**

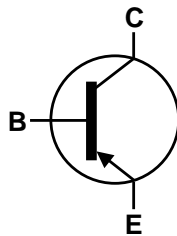
## Mechanical Data

- Package: X1-DFN1006-3
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – NiPdAu. Solderable per MIL-STD-202, Method 208 (e4)
- Weight: 0.0009 grams (Approximate)

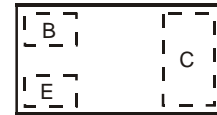
X1-DFN1006-3



Bottom View



Device Symbol

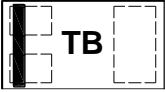
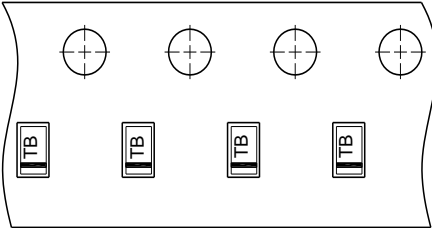
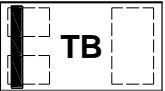
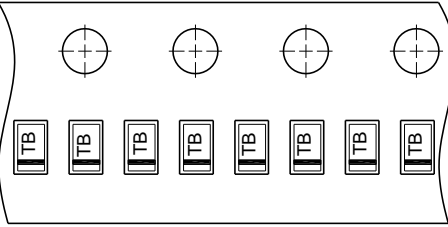
Top View  
Device Schematic

## Ordering Information (Note 4)

Part Number	Package	Marking	Reel Size (inches)	Tape Width (mm)	Packing	
					Qty.	Carrier
DSS3515M-7	X1-DFN1006-3	TB	7	8	3,000	Reel
DSS3515M-7B	X1-DFN1006-3	TB	7	8	10,000	Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

**Marking Information**

<p><b>DSS3515M-7</b></p>	 <p>TB = Product Type Marking Code</p> <p>Top View Bar Denotes Base and Emitter Side</p> 
<p><b>DSS3515M-7B</b></p>	 <p>TB = Product Type Marking Code</p> <p>Top View Bar Denotes Base and Emitter Side</p> 



DSS3515M

### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-15	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-15	V
Emitter-Base Voltage	V <sub>EBO</sub>	-6	V
Collector Current - Continuous	I <sub>C</sub>	-500	mA
Peak Pulse Collector Current	I <sub>CM</sub>	-1	A
Peak Base Current	I <sub>BM</sub>	-100	mA

### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	(Note 5)	400
		(Note 6)	1000
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub>	(Note 5)	310
		(Note 6)	120
Thermal Resistance, Junction to Lead	R <sub>θJL</sub>	120	°C/W
Operating and Storage and Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

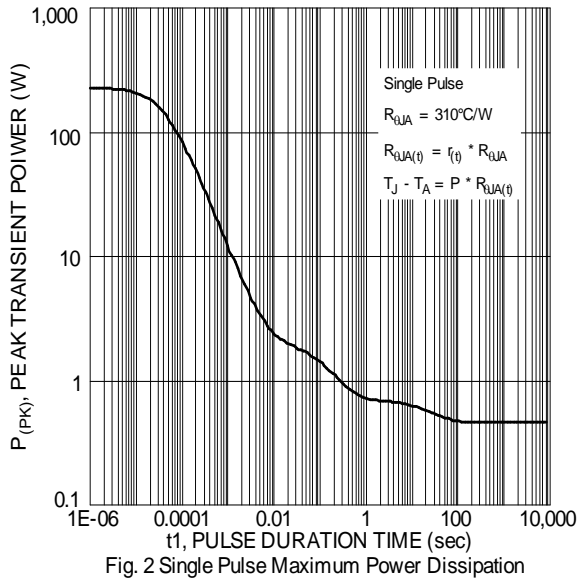
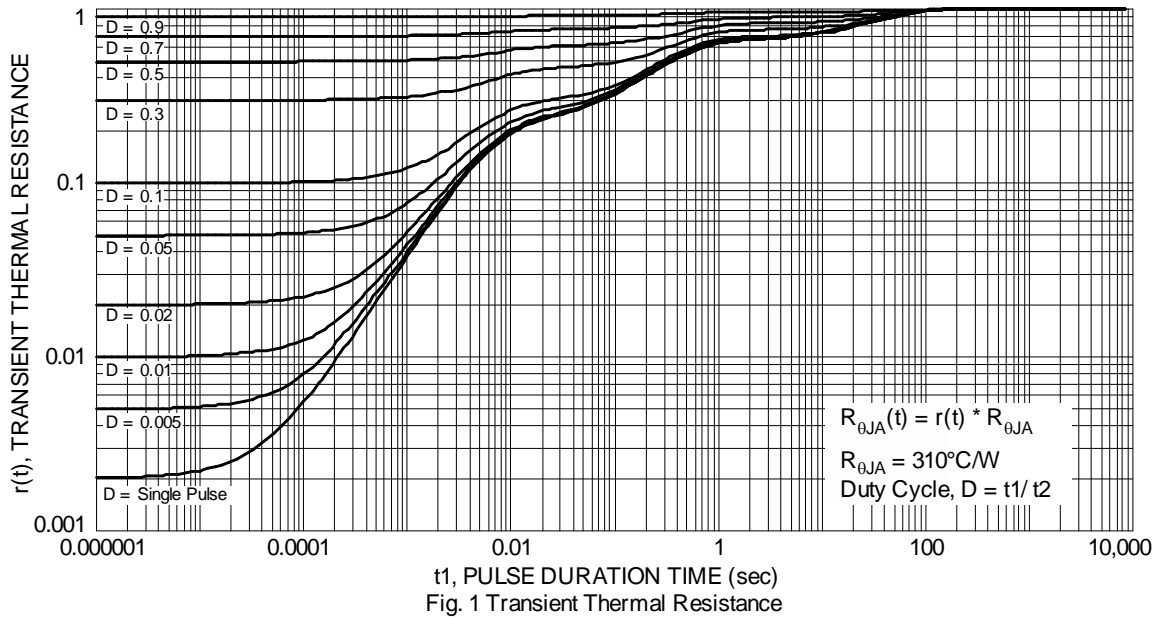
### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	200	V	B

- Notes:
5. For the device mounted on minimum recommended pad layout 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady state condition.
  6. Same as Note 5, except the exposed collector pad is mounted on 25mm x 25mm 2oz copper.
  7. Thermal resistance from junction to solder-point (on the exposed collector pad).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics





DSS3515M

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS</b>						
Collector-Base Breakdown Voltage	BV <sub>CB0</sub>	-15	—	—	V	I <sub>C</sub> = -100μA, I <sub>E</sub> = 0
Collector-Emitter Breakdown Voltage (Note 9)	BV <sub>CEO</sub>	-15	—	—	V	I <sub>C</sub> = -10mA, I <sub>B</sub> = 0
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	-6	—	—	V	I <sub>E</sub> = -100μA, I <sub>C</sub> = 0
Collector Cutoff Current	I <sub>CB0</sub>	—	—	-100 -50	nA μA	V <sub>CB</sub> = -15V, I <sub>E</sub> = 0 V <sub>CB</sub> = -15V, I <sub>E</sub> = 0, T <sub>A</sub> = +150°C
Emitter Cutoff Current	I <sub>EBO</sub>	—	—	-100	nA	V <sub>EB</sub> = -5V, I <sub>C</sub> = 0
<b>ON CHARACTERISTICS (Note 9)</b>						
DC Current Gain	h <sub>FE</sub>	200 150 90	— — —	— — —	—	V <sub>CE</sub> = -2V, I <sub>C</sub> = -10mA V <sub>CE</sub> = -2V, I <sub>C</sub> = -100mA V <sub>CE</sub> = -2V, I <sub>C</sub> = -500mA
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	— — —	— — —	-25 -150 -250	mV	I <sub>C</sub> = -10mA, I <sub>B</sub> = -0.5mA I <sub>C</sub> = -200mA, I <sub>B</sub> = -10mA I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Collector-Emitter Saturation Resistance	R <sub>CE(sat)</sub>	—	—	500	mΩ	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	—	—	-1.1	V	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Turn On Voltage	V <sub>BE(on)</sub>	—	—	-0.9	V	V <sub>CE</sub> = -2V, I <sub>C</sub> = -100mA
<b>SMALL SIGNAL CHARACTERISTICS</b>						
Output Capacitance	C <sub>obo</sub>	—	—	10	pF	V <sub>CB</sub> = -10V, f = 1.0MHz
Current Gain-Bandwidth Product	f <sub>T</sub>	100	340	—	MHz	V <sub>CE</sub> = -5V, I <sub>C</sub> = -100mA, f = 100MHz

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.



**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

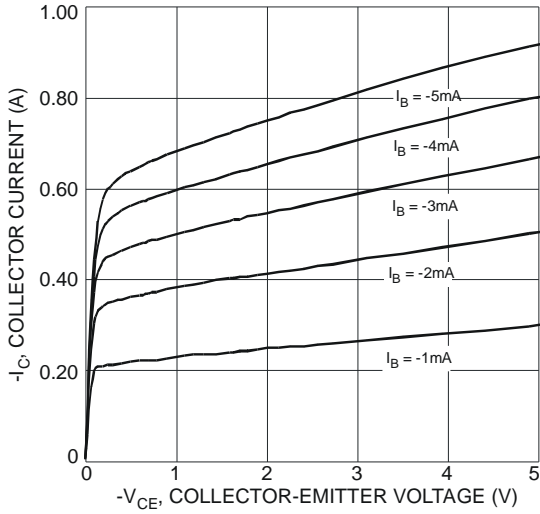


Fig. 3 Typical Collector Current vs. Collector-Emitter Voltage

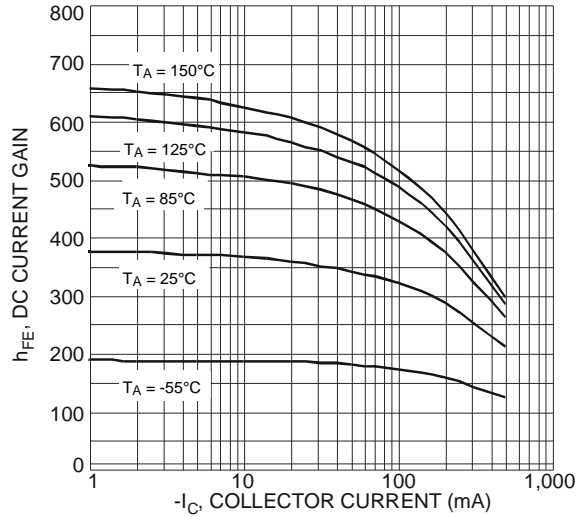


Fig. 4 Typical DC Current Gain vs. Collector Current

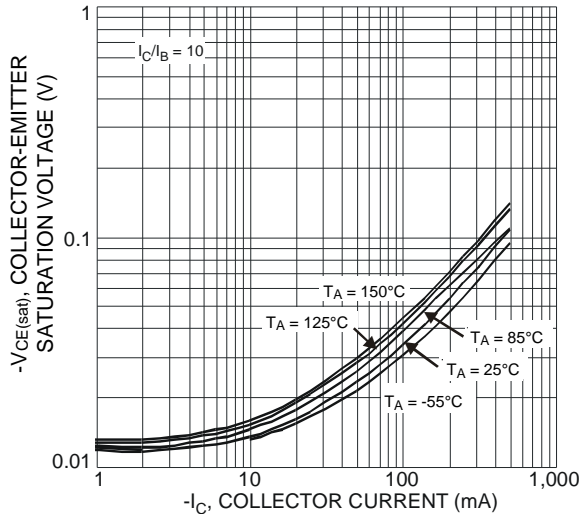


Fig. 5 Typical Collector-Emitter Saturation Voltage vs. Collector Current

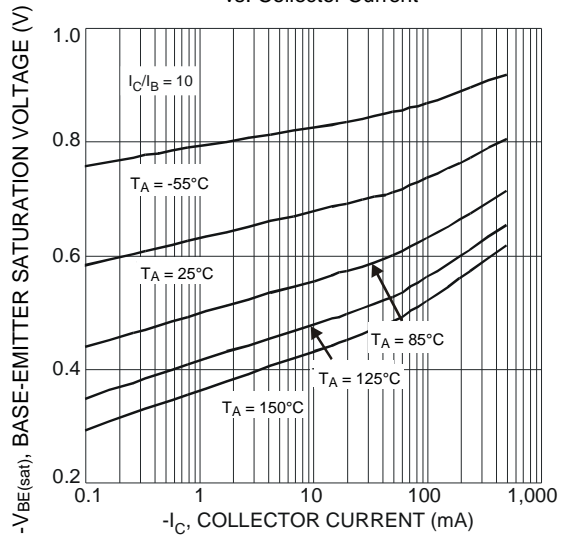


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

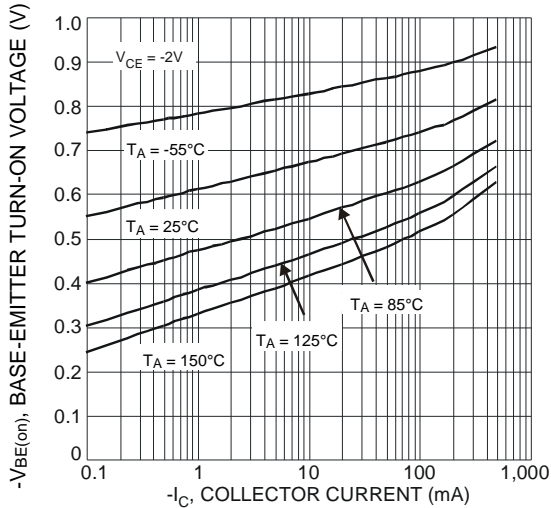


Fig. 7 Typical Base-Emitter Turn-On Voltage vs. Collector Current

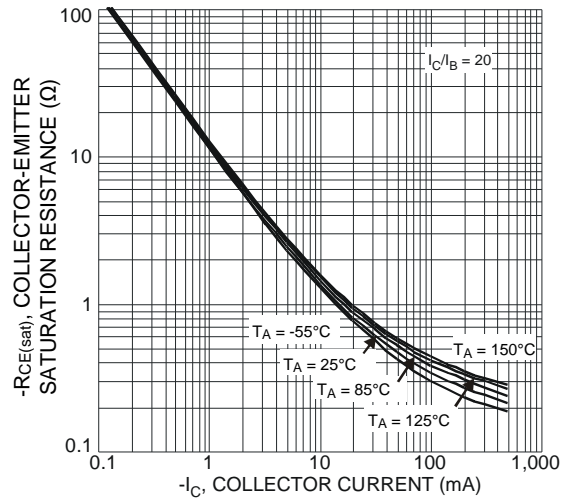


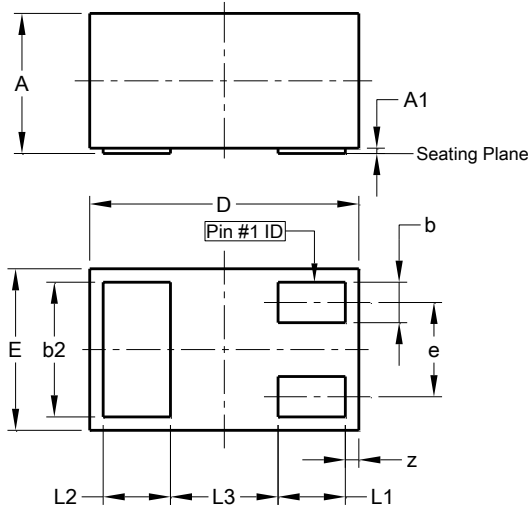
Fig. 8 Typical Collector-Emitter Saturation Resistance vs. Collector Current



## Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### X1-DFN1006-3

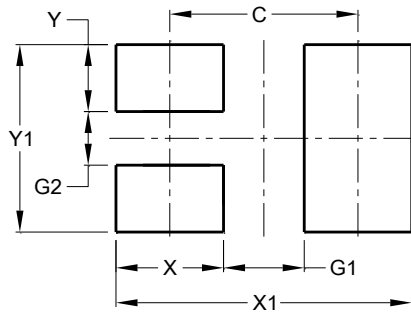


X1-DFN1006-3			
Dim	Min	Max	Typ
A	0.47	0.53	0.50
A1	0.00	0.05	0.03
b	0.10	0.20	0.15
b2	0.45	0.55	0.50
D	0.95	1.075	1.00
E	0.55	0.675	0.60
e	-	-	0.35
L1	0.20	0.30	0.25
L2	0.20	0.30	0.25
L3	-	-	0.40
z	0.02	0.08	0.05
<b>All Dimensions in mm</b>			

## Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

### X1-DFN1006-3



Dimensions	Value (in mm)
C	0.70
G1	0.30
G2	0.20
X	0.40
X1	1.10
Y	0.25
Y1	0.70

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